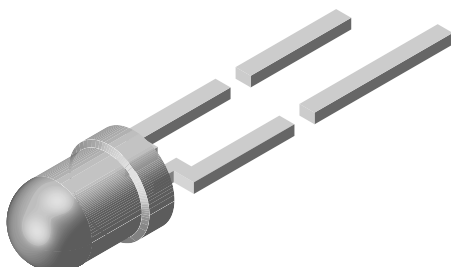


## High Speed Infrared Emitting Diode, 850 nm, Surface Emitter Technology



### DESCRIPTION

As part of the [SurfLight™](#) portfolio, the VSLY3850 is an infrared, 850 nm emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensity, high optical power and high speed, molded in a clear, untinted T1 plastic package.

### FEATURES

- Package type: leaded
- Package form: T-1, clear epoxy
- Dimensions: Ø 3 mm
- Peak wavelength:  $\lambda_p = 850$  nm
- High speed
- High radiant power
- High radiant intensity
- Angle of half intensity:  $\phi = \pm 18^\circ$
- Suitable for high pulse current operation
- Good spectral matching with CMOS cameras
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
**HALOGEN**  
**FREE**  
**GREEN**  
(5-2008)

### APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- 3D TV application
- Light curtains

### PRODUCT SUMMARY

| COMPONENT | $I_e$ (mW/sr) | $\phi$ (°) | $\lambda_p$ (nm) | $t_r$ (ns) |
|-----------|---------------|------------|------------------|------------|
| VSLY3850  | 70            | $\pm 18$   | 850              | 10         |

#### Note

- Test conditions see table “Basic Characteristics”

### ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS                       | PACKAGE FORM |
|---------------|-----------|-------------------------------|--------------|
| VSLY3850      | Bulk      | MOQ: 5000 pcs, 5000 pcs/bulk  | T-1          |
| VSLY3850-ASZ  | Ammopack  | MOQ: 10 000 pcs, 2000 pcs/box | T-1          |

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

| PARAMETER                             | TEST CONDITION                          | SYMBOL     | VALUE       | UNIT |
|---------------------------------------|-----------------------------------------|------------|-------------|------|
| Reverse voltage                       |                                         | $V_R$      | 5           | V    |
| Forward current                       |                                         | $I_F$      | 100         | mA   |
| Peak forward current                  | $t_p/T = 0.5$ , $t_p = 100 \mu\text{s}$ | $I_{FM}$   | 200         | mA   |
| Surge forward current                 | $t_p = 100 \mu\text{s}$                 | $I_{FSM}$  | 1           | A    |
| Power dissipation                     |                                         | $P_V$      | 190         | mW   |
| Junction temperature                  |                                         | $T_j$      | 100         | °C   |
| Operating temperature range           |                                         | $T_{amb}$  | -40 to +85  | °C   |
| Storage temperature range             |                                         | $T_{stg}$  | -40 to +100 | °C   |
| Soldering temperature                 | $t \leq 5$ s, 2 mm from case            | $T_{sd}$   | 260         | °C   |
| Thermal resistance junction / ambient | J-STD-051, leads 7 mm, soldered on PCB  | $R_{thJA}$ | 300         | K/W  |

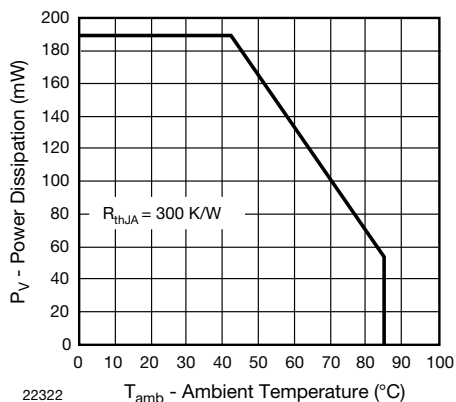


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

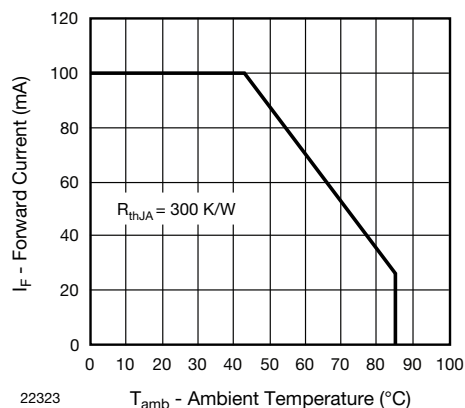


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| <b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                     |                  |                                    |          |      |               |
|-----------------------------------------------------------------------------------------------------|---------------------------------------------------------------------|------------------|------------------------------------|----------|------|---------------|
| PARAMETER                                                                                           | TEST CONDITION                                                      | SYMBOL           | MIN.                               | TYP.     | MAX. | UNIT          |
| Forward voltage                                                                                     | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$                        | $V_F$            | -                                  | 1.65     | 1.9  | V             |
|                                                                                                     | $I_F = 1\text{ A}$ , $t_p = 100\text{ }\mu\text{s}$                 | $V_F$            | -                                  | 2.9      | -    | V             |
| Temperature coefficient of $V_F$                                                                    | $I_F = 1\text{ mA}$                                                 | $TK_{VF}$        | -                                  | -1.45    | -    | mV/K          |
|                                                                                                     | $I_F = 10\text{ mA}$                                                | $TK_{VF}$        | -                                  | -1.25    | -    | mV/K          |
| Reverse current                                                                                     |                                                                     | $I_R$            | Not designed for reverse operation |          |      | $\mu\text{A}$ |
| Junction capacitance                                                                                | $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ ,<br>$E = 0\text{ mW/cm}^2$ | $C_J$            | -                                  | 125      | -    | pF            |
| Radiant intensity                                                                                   | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$                        | $I_e$            | 35                                 | 70       | 105  | mW/sr         |
|                                                                                                     | $I_F = 1\text{ A}$ , $t_p = 100\text{ }\mu\text{s}$                 | $I_e$            | -                                  | 600      | -    | mW/sr         |
| Radiant power                                                                                       | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$                        | $\phi_e$         | -                                  | 55       | -    | mW            |
| Temperature coefficient of radiant power                                                            | $I_F = 1\text{ mA}$                                                 | $TK_{\phi_e}$    | -                                  | -0.35    | -    | %/K           |
| Angle of half intensity                                                                             |                                                                     | $\phi$           | -                                  | $\pm 18$ | -    | $^{\circ}$    |
| Peak wavelength                                                                                     | $I_F = 30\text{ mA}$                                                | $\lambda_p$      | 840                                | 850      | 870  | nm            |
| Spectral bandwidth                                                                                  | $I_F = 30\text{ mA}$                                                | $\Delta\lambda$  | -                                  | 30       | -    | nm            |
| Temperature coefficient of $I_p$                                                                    | $I_F = 30\text{ mA}$                                                | $TK_{\lambda p}$ | -                                  | 0.25     | -    | nm            |
| Rise time                                                                                           | $I_F = 100\text{ mA}$ , 20 % to 80 %                                | $t_r$            | -                                  | 10       | -    | ns            |
| Fall time                                                                                           | $I_F = 100\text{ mA}$ , 20 % to 80 %                                | $t_f$            | -                                  | 10       | -    | ns            |

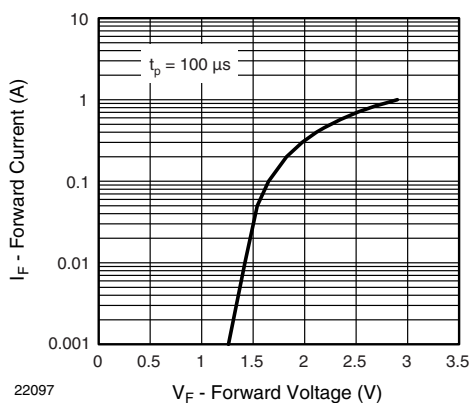
**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)


Fig. 3 - Forward Current vs. Forward Voltage

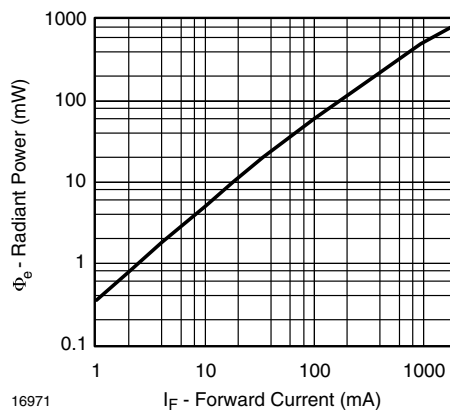


Fig. 6 - Radiant Power vs. Forward Current

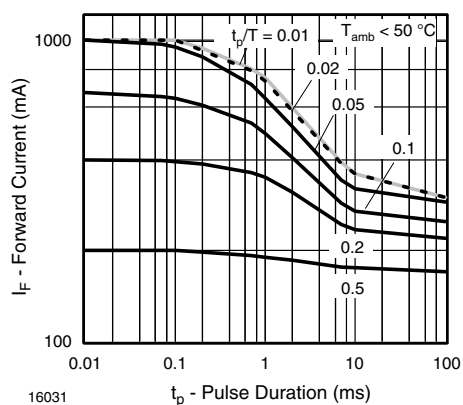


Fig. 4 - Pulse Forward Current vs. Pulse Duration

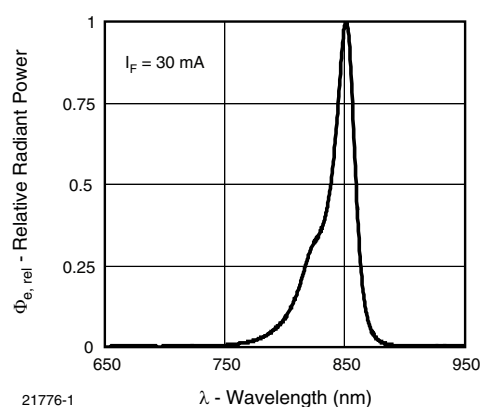


Fig. 7 - Relative Radiant Power vs. Wavelength

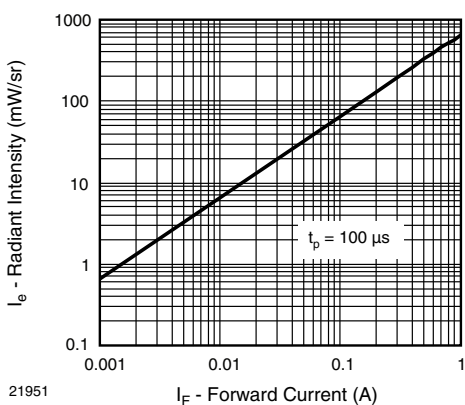


Fig. 5 - Radiant Intensity vs. Forward Current

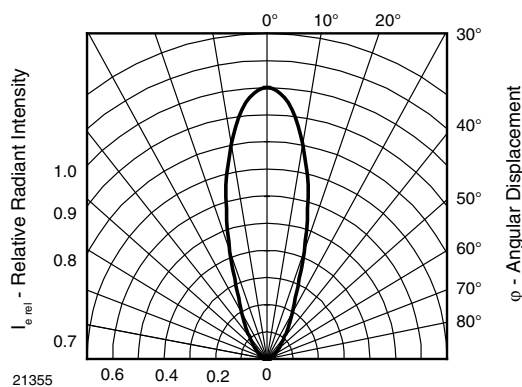
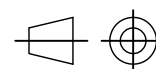
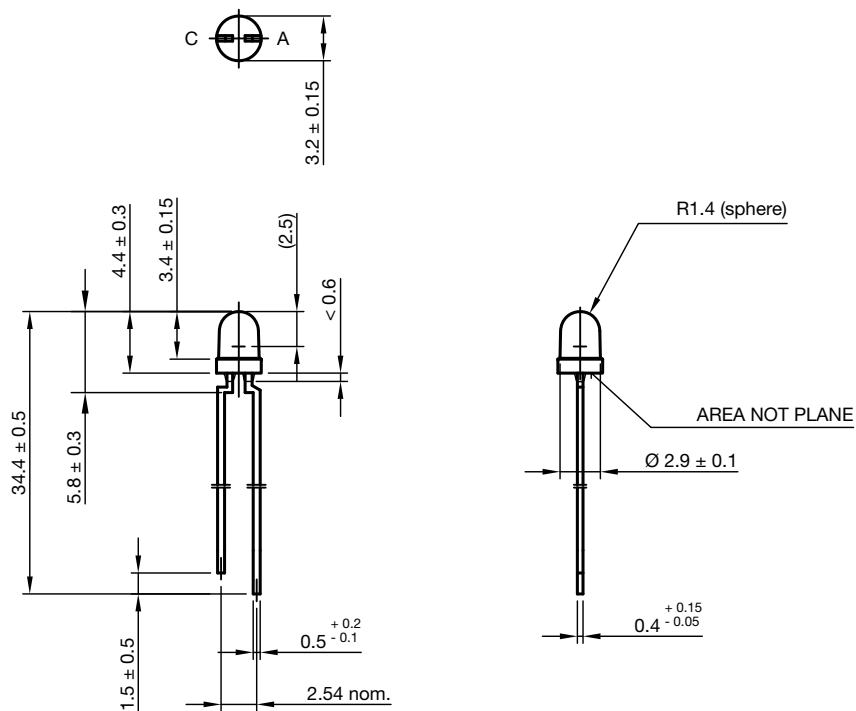


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

**PACKAGE DIMENSIONS** in millimeters


technical drawings  
according to DIN  
specifications

Drawing-No.: 6.544-5264.01-4  
Issue: 4; 28.07.14



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